# LIN Transceiver

## **General Description**

The single-wire transceiver AMIS-30600 is a monolithic integrated circuit in a SOIC-8 package. It works as an interface between the protocol controller and the physical bus.

The AMIS-30600 is especially suitable to drive the bus line in LIN systems in automotive and industrial applications. Further it can be used in standard ISO9141 systems.

In order to reduce the current consumption the AMIS-30600 offers a stand-by mode. A wake-up caused by a message on the bus pulls the INH-output high until the device is switched to normal operation

The transceiver is implemented in I2T100 technology enabling both high-voltage analog circuitry and digital functionality to co-exist on the same chip.

The AMIS-30600 provides an ultra-safe solution to today's automotive in-vehicle networking (IVN) requirements by providing unlimited short circuit protection in the event of a fault condition.

#### **Features**

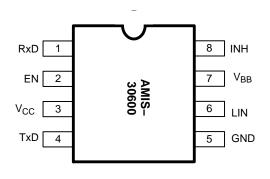
- LIN-Bus Transceiver
  - LIN compliant to specification rev. 1.3 and rev. 2.0
  - I2T high−voltage technology
  - Bus voltage ± 40 V
  - Transmission rate up to 20kbaud
  - ◆ SOIC-150-8 package
- Protection
  - Thermal shutdown
  - Indefinite short circuit protection to supply and ground
- Load dump protection (45 V)
- Power Saving
  - Operating voltage = 4.75 to 5.25 V
  - Power down supply current < 50 μA
- EMS Compatibility
  - Integrated filter and hysteresis for receiver
- EMI Compatibility
  - Integrated slope control for transmitter
  - Slope control dependant from Vbat to enable maximum capacitive load
- These are Pb-Free Devices



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#### **PIN ASSIGNMENT**



(Top View)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

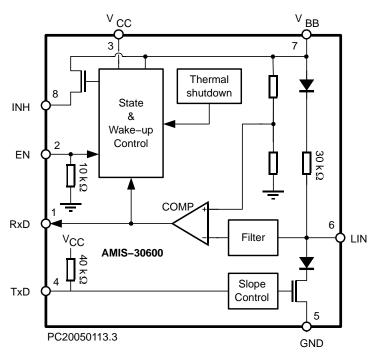


Figure 1. Block Diagram

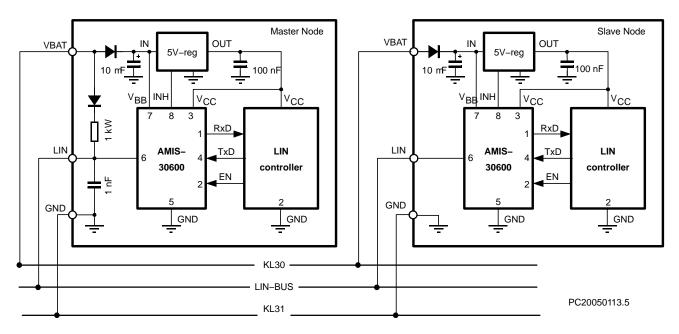


Figure 2. Application Diagram

### **Table 1. PIN LIST AND DESCRIPTIONS**

Pin	Name	Description		
1	RxD	Receive data output; low in dominant state		
2	EN	Enable input; transceiver in normal operation mode when high		
3	VCC	5V supply input		
4	TxD	Transmit data input; low in dominant state; internal 40 kΩ pullup		
5	GND	Ground		
6	LIN	LIN bus output/input; low in dominant state; internal 30 kΩ pullup		
7	VBB	Battery supply input		
8	INH	Inhibit output; to control a voltage regulator; becomes high when wake-up via LIN bus occurs		

#### **Table 2. ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		-0.3	+7	V
V <sub>BB</sub>	Battery Supply Voltage		-0.3	+40	V
$V_{LIN}$	DC Voltage at Pin LIN	0 < V <sub>CC</sub> < 5.50 V	-40	+40	V
V <sub>INH</sub>	DC Voltage at Pin INH	0 < V <sub>CC</sub> < 5.50 V	-0.3	V <sub>BB</sub> + 0.3	V
$V_{TxD}$	DC Voltage at Pin TxD	0 < V <sub>CC</sub> < 5.50 V	-0.3	V <sub>CC</sub> + 0.3	V
V <sub>RxD</sub>	DC Voltage at Pin RxD	0 < V <sub>CC</sub> < 5.50 V	-0.3	V <sub>CC</sub> + 0.3	V
V <sub>EN</sub>	DC Voltage at Pin EN	0 < V <sub>CC</sub> < 5.50 V	-0.3	V <sub>CC</sub> + 0.3	V
V <sub>esd(LIN)</sub>	Electrostatic Discharge Voltage at LIN Pin	(Note 1)	-4	+4	kV
V <sub>esd</sub>	Electrostatic Discharge Voltage at All Other Pins	(Note 1)	-4	+4	kV
V <sub>tran(LIN)</sub>	Transient Voltage at Pin LIN	(Note 2)	-150	+150	V
V <sub>tran(VBB)</sub>	Transient Voltage at Pin V <sub>BB</sub>	(Note 3)	-150	+150	V
T <sub>amb</sub>	Ambient Temperature		-40	+150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Standardized Human Body Model system ESD pulses in accordance to IEC 1000.4.2.

2. Applied transient waveforms in accordance with "ISO 7637 parts 1 & 3", capacitive coupled test pulses 1 (–100 V), 2 (+100 V), 3a (–150 V),

- and 3b (+150 V). See Figure 8.
- 3. Applied transient waveforms in accordance with "ISO 7637 parts 1 & 3", direct coupled test pulses 1 (-100 V), 2 (+75 V), 3a (-150 V), 3b (+150 V), and 5 (+80 V). See Figure 8.

# **Table 3. OPERATING RANGE**

Symbol	Parameter		Тур	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.75		+5.25	V
V <sub>BB</sub>	Battery Supply Voltage	7.3		+18	V
TJ	Maximum Junction Temperature	-40		+150	°C
T <sub>jsd</sub>	Thermal Shutdown Temperature	+150	+170	+190	°C
R <sub>thj-a</sub>	Thermal Resistance Junction-to-Ambient		185		°C/W

#### APPLICATION INFORMATION

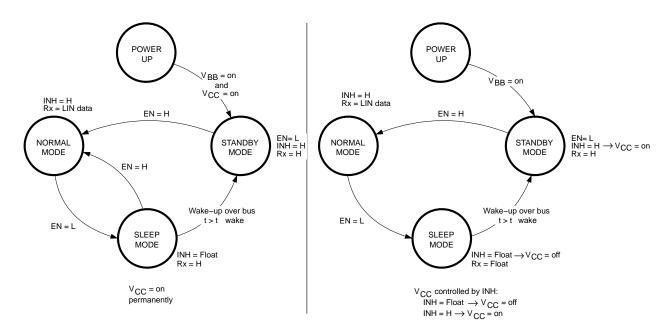


Figure 3. State Diagrams

The AMIS–30600 has a slope which depends of the supply  $V_{bat}$ . This implementation guarantees biggest slope–time under all load conditions. The rising slope has to be slower then the external RC–time–constant, otherwise the slope will be terminated by the RC–time–constant and no longer by the internal slope–control. This would affect the symmetry of the bus–signal and would limit the maximum allowed bus–speed.

A capacitor of 10  $\mu F$  at the supply voltage input VB buffers the input voltage. In combination with the required reverse polarity diode this prevents the device from detecting power down conditions in case of negative transients on the supply line.

In order to reduce the current consumption, the AMIS-30600 offers a sleep operation mode. This mode is selected by switching the enable input EN low (see Figure 4).

An external voltage regulator can be controlled via the INH output in order to minimize the current consumption of the whole application in sleep mode (see Figure 2). A wake-up caused by a message on the communication bus automatically enables the voltage regulator by switching the INH output high (see Figure 3). In case the voltage regulator control input is not connected to the INH output, or the microcontroller is active respectively, the AMIS-30600 can be set in normal operation mode by EN = H (see Figure 3).

**Table 4. DC CHARACTERISTICS**  $V_{CC}$  = 4.75 V to 5.25 V;  $V_{BB}$  = 7.3 V to 18 V, $V_{EN}$  <  $V_{ENon}$ ,  $T_A$  = -40°C to +125°C;  $R_L$  = 500  $\Omega$  unless specified otherwise. All voltages with respect to ground, positive current flowing into pin, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
SUPPLY (F	Pin V <sub>CC</sub> and Pin V <sub>BB</sub> )		•		•	
I <sub>CC</sub>	5 V Supply Current	Dominant; $V_{TxD} = 0 V$ Recessive; $V_{TxD} = V_{CC}$		400 250	700 500	μА
I <sub>BB</sub>	Battery Supply Current	Dominant; $V_{TxD} = 0 \text{ V}$ Recessive; $V_{TxD} = V_{CC}$		1 100	1.5 200	mA μA
I <sub>BB</sub>	Battery Supply Current	Sleep Mode; V <sub>EN</sub> = 0 V		35	55	μΑ
I <sub>CC</sub>	5 V Supply Current	Sleep Mode; V <sub>EN</sub> = 0 V		0.25	1	μΑ
TRANSMI	TTER DATA INPUT (Pin TxD)					
V <sub>IH</sub>	High-Level Input Voltage	Output Recessive	0.7 x V <sub>CC</sub>	-	V <sub>CC</sub>	V
$V_{IL}$	Low-Level Input Voltage	Output Dominant	0	-	0.3 x V <sub>CC</sub>	V
R <sub>TxD,pu</sub>	Pullup Resistor to V <sub>CC</sub>		24		60	k
RECEIVER	R DATA OUTPUT (Pin RxD)					
V <sub>OH</sub>	High-Level Output Voltage	I <sub>RXD</sub> = -10 mA	0.8 x V <sub>CC</sub>		V <sub>CC</sub>	V
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>RXD</sub> = 5 mA	0		0.2 x V <sub>CC</sub>	V
ENABLE I	NPUT (Pin EN)					-
V <sub>EN,on</sub>	High-Level Input Voltage	Normal Mode	0.7 x V <sub>CC</sub>	-	V <sub>CC</sub>	V
V <sub>EN,off</sub>	Low-Level Input Voltage	Low Power Mode	0	-	0.3 x V <sub>CC</sub>	V
R <sub>EN,pd</sub>	Pulldown Resistor-to-GND		6	10	15	k
INHIBIT O	UTPUT (Pin INH)					
$V_{\text{INH,d}}$	High-Level Voltage Drop: V <sub>INH,d</sub> = V <sub>BB</sub> - V <sub>INH</sub>	I <sub>INH</sub> = - 0.15 mA		0.5	1.0	V
I <sub>INH,Ik</sub>	Leakage Current	Sleep Mode; V <sub>INH</sub> = 0 V	-5.0	-	5.0	μΑ
BUS LINE	(Pin LIN)					
V <sub>bus,rec</sub>	Recessive Bus Voltage at Pin LIN	$V_{TxD} = V_{CC}$	0.9 x V <sub>BB</sub>	_	V <sub>BB</sub>	V
V <sub>bus,dom</sub>	Dominant Output Voltage at Pin LIN	$\begin{array}{c} V_{TxD} = 0 \; V \; ; \; V_{BB} = 7.3 \; V \\ V_{TxD} = 0 \; V ; \; V_{BB} = 18 \; V ; \\ R_L = 500 \; \Omega \end{array}$	0	-	1.2 2.0	V
I <sub>bus,sc</sub>	Bus Short-Circuit Current	V <sub>bus,short</sub> = 18 V	40	85	130	mA
I <sub>bus,lk</sub>	Bus Leakage Current	$V_{CC} = V_{BB} = 0V$ ; $V_{bus} = -8 V$ $V_{CC} = V_{BB} = 0V$ ; $V_{bus} = 20 V$	-400	-200 5	20	μА
R <sub>bus</sub>	Bus Pullup Resistance; Note 4	$V_{TxD} = 0 V$	20	30	47	kΩ
V <sub>bus,rd</sub>	Receiver Threshold: Recessive-to-Dominant		0.4 x V <sub>BB</sub>	0.48 x V <sub>BB</sub>	0.6 x V <sub>BB</sub>	V
V <sub>bus,dr</sub>	Receiver Threshold: Dominant–to–Recessive		0.4 x V <sub>BB</sub>	0.52 x V <sub>BB</sub>	0.6 x V <sub>BB</sub>	V
Vq	Receiver Hysteresis	V <sub>bus,hys</sub> = V <sub>bus,rec</sub> - V <sub>bus,dom</sub>	0.05 x V <sub>BB</sub>	0.08 x V <sub>BB</sub>	0.175 x V <sub>BB</sub>	V
V <sub>WAKE</sub>	Wake-up Threshold Voltage		0.4 x V <sub>BB</sub>		0.6 x V <sub>BB</sub>	V

<sup>4.</sup> Guaranteed by design. The total resistance of the pullup resistor and the serial diode is measured on ATE.

Table 5. AC ELECTRICAL CHARACTERISTICS ACCORDING TO LIN V13  $V_{CC}$  = 4.75 V to 5.25 V;  $V_{BB}$  = 7.3 V to 18 V, $V_{EN}$  <  $V_{ENon}$ ,  $T_A$  = -40°C to +125°C;  $R_L$  = 500  $\Omega$  unless otherwise specified. Load for slope definitions (typical loads) = [L1] 1 nF 1 kΩ / [L2] 6.8 nF 600  $\Omega$  / [L3] 10 nF 500  $\Omega$ .

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t_slope_F	Slope Time Falling Edge; (Note 5)	See Figure 5	4	-	24	μS
t_slope_R	Slope Time Rising Edge; (Note 5)	See Figure 5	4	-	24	μS
t_slope_Sym	Slope Time Symmetry; (Note 5)	t_slope_F - t_slope_R	-8	-	+8	μS
T_rec_F	Propagation Delay Bus Dominant to RxD = Low; (Note 6)	See Figures 4 and 5		2	6	μs
T_rec_R	Propagation Delay Bus Recessive to RxD = High; (Note 6)	See Figures 4 and 5		6	6	μS
t <sub>WAKE</sub>	Wake-up Delay Time		30	100	200	μS

<sup>5.</sup> Guaranteed by design; not measured for all supply/load combinations on ATE.

Table 6. AC ELECTRICAL CHARACTERISTICS ACCORDING TO LIN v2.0  $V_{CC}$  = 4.75 V to 5.25 V;  $V_{BB}$  = 7.3 V to 18 V, $V_{EN}$  <  $V_{ENon}$ ,  $V_{ENon}$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
DYNAMIC RE	DYNAMIC RECEIVER CHARACTERISTICS ACCORDING TO LIN v2.0								
trx_pdr	Propagation Delay Bus Dominant to RxD = Low; (Note 7)	See Figure 6			6	μs			
trx_pdf	Propagation Delay Bus Recessive to RxD = High; (Note 7)	See Figure 6			6	μS			
trx_sym	Symmetry of Receiver Propagation Delay	trx_pdr – trx_pdf	-2	_	+2	μs			
DYNAMIC TRA	DYNAMIC TRANSMITTER CHARACTERISTICS ACCORDING TO LIN v2.0								
D1	Duty Cycle 1 = t <sub>Bus_rec(min)</sub> /(2 x t <sub>Bit</sub> ); See Figure		0.396		0.5				
D1	Duty Cycle 1 = t <sub>Bus_rec(min)</sub> /(2 x t <sub>Bit</sub> ); See Figure 6	$\begin{array}{l} THRec(max) = 0.744 \text{ x V}_{bat}; \\ THDom(max) = 0.581 \text{ x V}_{bat}; V_{bat} \\ = 7.0 \text{ V to 18 V; } t_{Bit} = 50  \mu s \\ THRec(max) = 0.744 \text{ x V}_{bat}; \\ THDom(max) = 0.581 \text{ x V}_{bat}; V_{bat} \\ = 7.0 \text{ V; } t_{Bit} = 50  \mu s; \\ t_{amb} = -40 ^{\circ} \text{C} \end{array}$	0.366		0.5				
D2	Duty Cycle 2 = t <sub>Bus_rec(max)</sub> /(2 x t <sub>Bit</sub> ); See Figure 6	THRec(min) = 0.284 x V <sub>bat</sub> ; THDom(min) = 0.422 x V <sub>bat</sub> ;V <sub>bat</sub> = 7.6 V to 18 V; t <sub>Bit</sub> = 50 μs;	0.5		0.581				

<sup>7.</sup> Not measured on ATE.

<sup>6.</sup> Not measured on ATE.

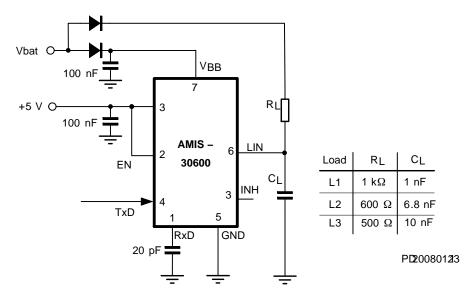


Figure 4. Test Circuit for Timing Characteristics

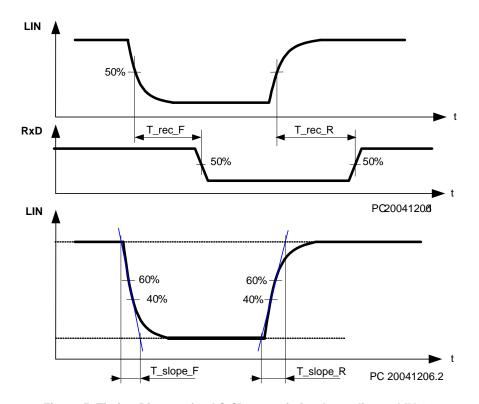


Figure 5. Timing Diagram for AC Characteristics According to LIN 1.3

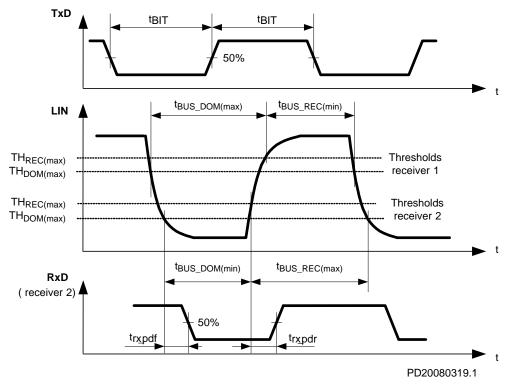
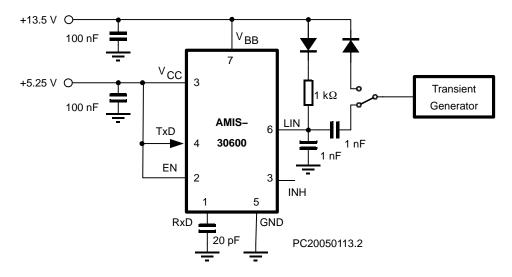


Figure 6. Timing Diagram for AC Characteristics According to LIN 2.0

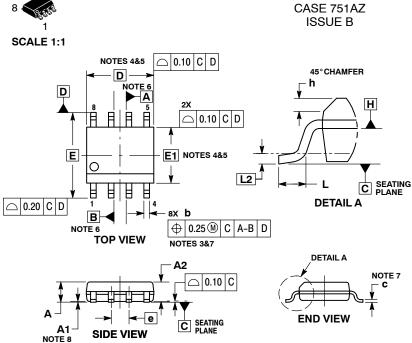


**Figure 7. Test Circuit for Transient Measurements** 

# **DEVICE ORDERING INFORMATION**

Part Number	Temperature Range	Package Type	Shipping <sup>†</sup>
AMIS30600LINI1G	−40°C − 125°C	SOIC-8 (Pb-Free)	96 Tube / Tray
AMIS30600LINI1RG	−40°C − 125°C	SOIC-8 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



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**DATE 18 MAY 2015** 

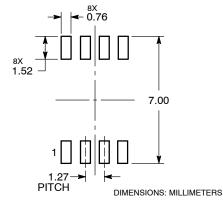
#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2
- CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.004 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
- DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.006 mm PER SIDE. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.010 mm PER SIDE.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM. DIMENSIONS D AND E1 ARE DETERMINED AT THE OUTER-MOST EXTREMES OF THE PLASTIC BODY AT DATUM H.

  DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM H.
- DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 TO 0.25 FROM THE LEAD TIP.
- A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

	MILLIMETERS			
DIM	MIN MAX			
Α		1.75		
A1	0.10	0.25		
A2	1.25			
b	0.31	0.51		
С	0.10	0.25		
D	4.90	BSC		
E	6.00	BSC		
E1	3.90	BSC		
е	1.27	BSC		
h	0.25	0.41		
L	0.40	1.27		
L2	0.25 BSC			

#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **GENERIC** MARKING DIAGRAM\*



XXXXX = Specific Device Code

= Assembly Location Α

= Wafer Lot L Υ = Year

W

= Work Week = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

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NCV7420D26R2G MCP2003A-E/MD MCP2003A-E/P MCP2003A-E/SN MCP2003-E/P MCP2004A-E/P MCP2004A-E/SN MCP2004
E/MD MCP2004-E/P MCP2004-E/SN MCP2021-330E/MD MCP2021-330E/P MCP2021-330E/SN MCP2021-500E/SN MCP2021A
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TJA1021T/20/C.118 STLD1TR TLIN1022DMTTQ1